2 A Three-quadrant triacs high commutation

Rev. 01 — 7 February 2008

Product data sheet

1. Product profile

1.1 General description

Passivated high commutation triacs in a SOT186A 'full pack' plastic package. These triacs balance the requirements of commutation performance and gate sensitivity. The 'sensitive' gate E series and 'logic level' D series are intended for interfacing with low-power drivers, including microcontrollers.

1.2 Features

Sensitive gate

 Very high commutation performance maximized at each gate sensitivity

1.3 Applications

Motor control

1.4 Quick reference data

- V_{DRM} ≤ 600 V (BTA202X-600D)
- V_{DRM} ≤ 600 V (BTA202X-600E)
- V_{DRM} ≤ 800 V (BTA202X-800D)
- V_{DRM} ≤ 800 V (BTA202X-800E)
- IT(RMS) $\leq 2 \text{ A}$

Solenoid driver

High immunity to dV/dt

High isolation voltage

- I_{GT} \leq 5 mA (BTA202X-600D)
- IGT \leq 10 mA (BTA202X-600E)
- I_{GT} \leq 5 mA (BTA202X-800D)
- I_{GT} \leq 10 mA (BTA202X-800E)



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Pinning information 2.

Table 1.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	main terminal 1 (T1)		N 1
2	main terminal 2 (T2)	mb	T2-T1
3	gate (G)		`G sym051
mb	mounting base (isolated)		

SOT186A (TO-220F)

 $\begin{bmatrix} 1 & 0 & 0 \\ 0 & 0 & 0 \\ 1 & 2 & 3 \end{bmatrix}$

Ordering information 3.

Table 2. **Ordering information**

Table 2. Order	ing informat	ion a transformed and the second	
Type number	Package		
	Name	Description	Version
BTA202X-600D	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole	SOT186A
BTA202X-600E		3-lead TO-220 'full pack'	
BTA202X-800D			
BTA202X-800E			

Limiting values 4.

Table 3. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage	BTA202X-600D; BTA202X-600E	<u>[1]</u> _	600	V
		BTA202X-800D; BTA202X-800E		800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _h ≤ 110 °C; see <u>Figure 4</u> and <u>5</u>	-	2	А
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_j = 25 \text{ °C prior to}$ surge; see Figure 2 and 3			
		t = 20 ms	-	14	А
		t = 16.7 ms	-	15.4	А
l ² t	I ² t for fusing	t _p = 10 ms	-	0.98	A ² s
dl _T /dt	rate of rise of on-state current	I_{TM} = 1.5 A; I_G = 0.2 A; d I_G /dt = 0.2 A/µs	-	100	A/μs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W

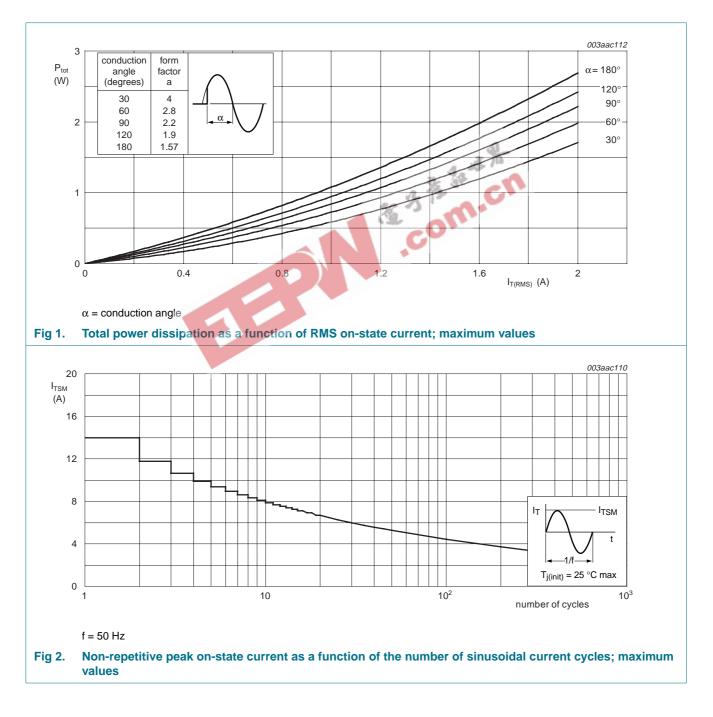
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Table 3. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

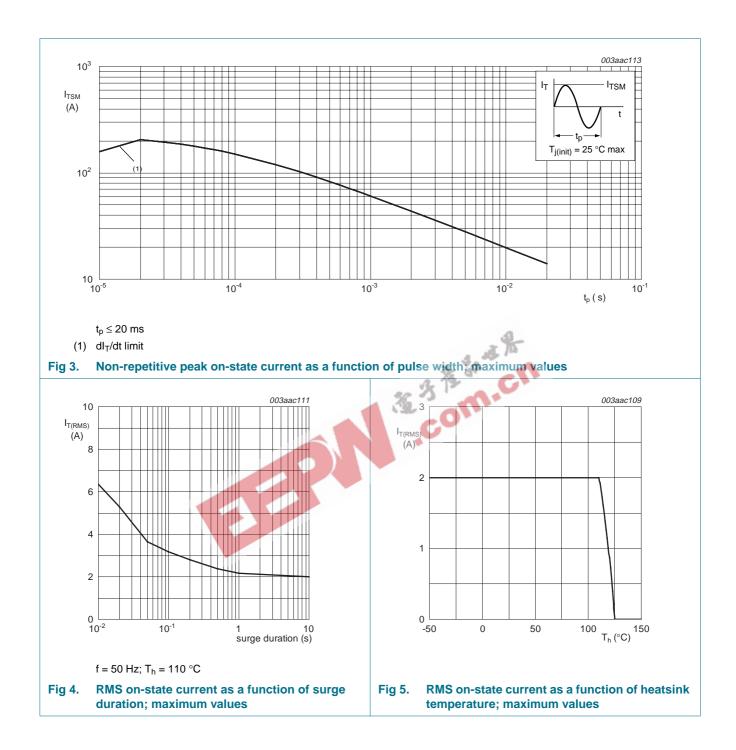
Symbol	Parameter	Conditions	Min	Max	Unit
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

 Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 A/μs.



BTA202X series D and E

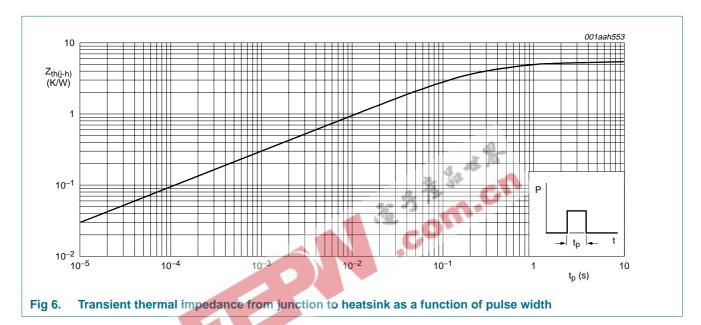
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5. Thermal characteristics

Table 4.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to heatsink	bidirectional; see Figure 6	-	-	5.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	55	-	K/W



6. Isolation characteristics

Table 5. Isolation limiting values and characteristics

 $T_h = 25 \circ C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	from all three terminals to external heatsink; f = 50 Hz to 60 Hz; sinusoidal waveform; RH \leq 65 %; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	from pin 2 to external heatsink; f = 1 MHz	-	10	-	pF

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7. Static characteristics

Table 6. Static characteristics

 $T_i = 25 \circ C$ unless otherwise specified.

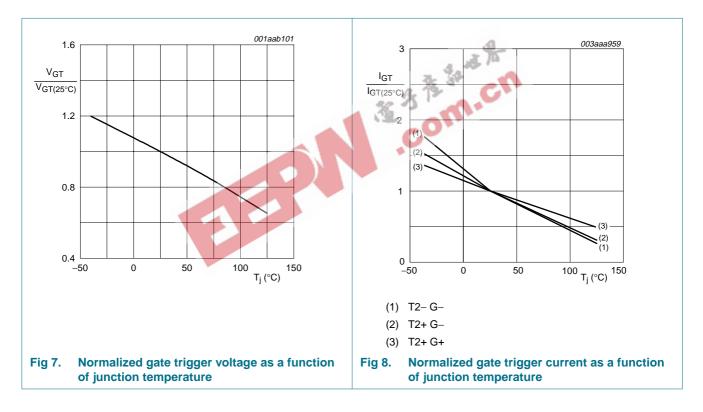
Symbol	Parameter	Conditions		BTA202X-600D BTA202X-800D			BTA202X-600E BTA202X-800E		
			Min	Тур	Max	Min	Тур	Max	1
I _{GT}	gate trigger current	$V_D = 12 V; I_T = 0.1 A;$ see <u>Figure 8</u>							1
		T2+ G+	0.25	-	5	0.5	-	10	mA
		T2+ G–	0.25	-	5	0.5	-	10	mA
		T2– G–	0.25	-	5	0.5	-	10	mA
IL	latching current	V _D = 12 V; I _{GT} = 0.1 A; see <u>Figure 10</u>							
		T2+ G+	-	-	5	-	-	12	mA
		T2+ G–	-	-	10	-	-	20	mA
		T2– G–	-	-	5	-	-	12	mA
Ι _Η	holding current	V _D = 12 V; I _{GT} = 0.1 A; see <u>Figure 11</u>	a. 3	15 3P	5		-	12	mA
V _T	on-state voltage	I _T = 3 A; see <u>Figure 9</u>	26 23	1.63	2	-	1.63	2	V
V_{GT}	gate trigger voltage	$V_D = 12 V; I_T = 0.1 A;$ see <u>Figure 7</u>	C	0.7	1.5	-	0.7	1.5	V
		$V_D = 400 \text{ V}; I_T = 0.1 \text{ A};$ $T_j = 125 \text{ °C}$	0.2	0.3	-	0.2	0.3	-	V
I _D	off-state current	V _D = V _{DRM(max)} ; T _j = 125 °C	-	0.1	0.5	-	0.1	0.5	mA

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8. Dynamic characteristics

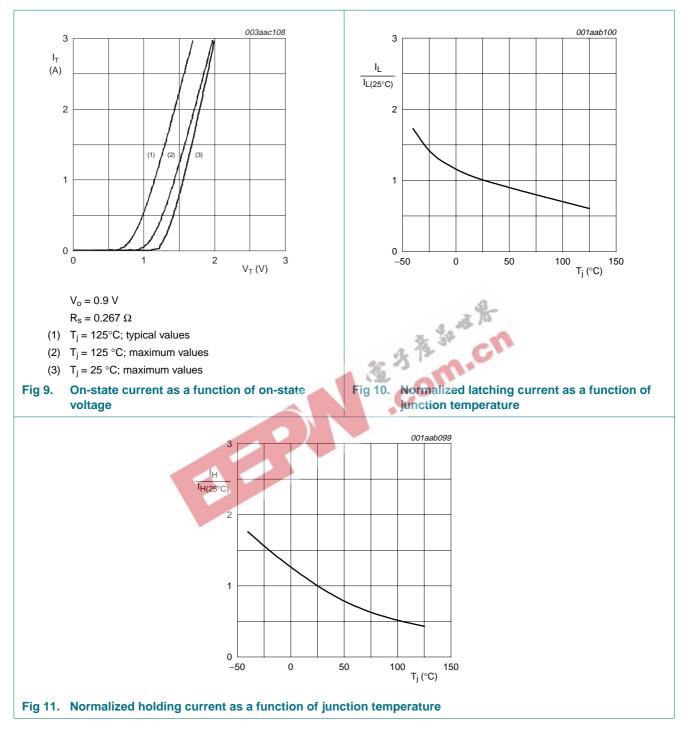
Table 7. Dynamic characteristics

Symbol Parameter		Conditions		BTA202X-600D BTA202X-800D			BTA202X-600E BTA202X-800E		
				Тур	Max	Min	Тур	Max]
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 0.67 \times V_{DRM(max)}$; T _j = 125 °C; exponential waveform; R _(G-MT1) = 220 Ω	-	350	-	-	500	-	V/µs
dl _{com} /dt	dl _{com} /dt rate of change of commutating	V_{DM} = 400 V; T _j = 125 °C; I _{T(RMS)} = 2 A; dV _{com} /dt = 20 V/µs; gate open circuit	1.0	-	-	2.0	-	-	A/ms
current		V_{DM} = 400 V; T _j = 125 °C; I _{T(RMS)} = 2 A; dV _{com} /dt = 10 V/µs; gate open circuit	1.2	-	-	2.3	-	-	A/ms
t _{gt}	gate-controlled turn-on time	$\begin{split} I_{TM} &= 20 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A}; \\ dI_G/dt &= 5 A/\mu s \end{split}$	-	2	-	-	2	-	μs



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9. Package information

Refer to mounting instructions for F-pack packages.

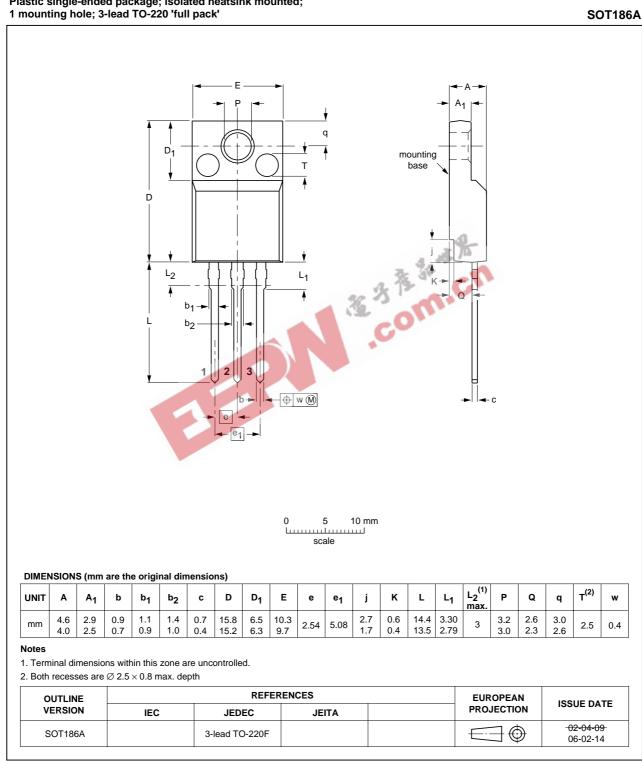
Epoxy meets UL94 V-0 at 3.175 mm.

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10. Package outline



Plastic single-ended package; isolated heatsink mounted;

Fig 12. Package outline SOT186A (3-lead TO-220F)

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11. Revision history

Table 8. Revision hist	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA202X_SER_D_E_1	20080207	Product data sheet	-	-



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12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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